

SIEGERT WAFER GmbH, Charlottenburger Allee 7, 52068 Aachen, GERMANY

CNR-NANO
Istituto Nanoscienze NEST
Piazza San Silvestro 12
56127 Pisa
ITALY

Order Acknowledgement

Document No. 210101	Date 22.09.2021	Page 1 / 2
Order No. 9170000313-314	Our Reference 27474.kk	
SW Contact Kevin Kalz kevin.kalz@siegertwafer.de	Phone +49 241 943 297-15	
Customer No. 11879	VAT-ID IT02118311006	
Contact Person Prof. Lucia Sorba lucia.sorba@nano.cnr.it	Phone +39 050 509 418	
Invoice Address CONSIGLIO NAZIONALE DELLE RICERCHE !!C.N.R. PIAZZALE ALDO MORO 7 00185 ROMA RM ITALY		

The detailed Specification can be found on the following page(s)

Currency: EUR

Description	Quantity	Unit	Price	Total
1 Si-Wafer 2"/Intrinsic/<100>/>10,000/279±25/DSP/TTV<10/300nm wet SiO2	25	pcs	39,70	992,50
Lead Time: 2-4 weeks				
2 Si-Wafer 2N0/As/<0.005/279±25/SSP/TTV<10	5	pcs	29,80	149,00
Lead Time: 3-4 weeks				
3 Shipping and Packaging (Europe)	1	pc	45,00	45,00

Contract identification code (CIG): Z51330911A;
Unified project code (CUP)1: B52F17002450006, (CUP)2: B56C19000010006

HS Code: 381 800 1000

Subtotal	1.186,50
Net Amount	1.186,50
Total (EUR)	1.186,50

Based on Document No. 130022 from 30.08.2021

Our Standard Terms and Conditions of Sale and Delivery apply, accessible at www.terms.siegertwafer.com

We will be glad to provide you with a printed version upon request

INCOTERM 2020	Payment Terms
EXW-Aachen-GER	21 days net

Remarks

- Please always state our reference number on all documents and in all e-mails: 27474.kk
- Apparent defects must be reported in writing within a period of 5 days from receipt of the goods (Standard Terms and Conditions, clause 8.3)

Thank you for your order!



SIEGERT WAFER GmbH
Charlottenburger Allee 7
52068 Aachen, GERMANY

General Manager:
Dipl.-Ing. Marcus Siegert, Michael Kinch

Phone +49 241 943 297-00
Fax +49 241 943 297-19
Email info@siegertwafer.de
VAT-ID DE815357871
Register HRB 17499

Bank Name Sparkasse Aachen
Account 47733993
Bank Code 39050000
Swift/BIC AACSD33XXX
IBAN DE97 3905 0000 0047 7339 93



Item	Specification	Value
1	Diameter:	50.8 ±0.3 mm
	Material:	Silicon
	Growth:	FZ
	Grade:	Prime
	Type/Dopant:	Intrinsic
	Orientation:	<100> ±0.5°
	Resistivity:	>10,000 Ohm-cm
	Thickness:	279 ±25 µm
	Surface Finish:	Double Side Polished
	Flats:	1 primary Flat, SEMI-Std.
	TTV:	<10 µm
	Bow:	<30 µm
	Warp:	<30 µm
	Particles ≥0.3 µm:	<15
	Packaging:	Cassettes
	Coating:	3,000 Å ±5% Wet Thermal Oxide
	Attention:	Original particle specification is only valid prior coating
2	Diameter:	50.8 ±0.3 mm
	Material:	Silicon
	Growth:	CZ
	Grade:	Prime
	Type/Dopant:	N/As
	Orientation:	<100> ±0.5°
	Resistivity:	<0.005 Ohm-cm
	Thickness:	279 ±25 µm
	Surface Finish:	Single Side Polished
	Flats:	1 Primary Flat, SEMI-Std.
	TTV:	<10 µm
	Bow:	<30 µm
	Warp:	<30 µm
	Particles ≥0.5 µm:	<10
	Packaging:	3-Part Cassettes

